NSN 5962-01-116-5778

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Dl	Length:
BOOV	i enain.

Between 0.660 inches and 0.785 inches

Body Width:

Between 0.220 inches and 0.280 inches

Body Height:

Between 0.140 inches and 0.180 inches

Maximum Power Dissipation Rating:

10.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Walleye i er 02387

Features Provided:

Hermetically sealed and monolithic and positive outputs

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

Quad 2 input

Design Function And Quantity:

4 gate, nand

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

22.00 nanoseconds propagation delay time, low to high level output and 15.00 nanoseconds propagation delay time, high to low level output

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

14 printed circuit

Specification Data:

81349-mil-m-38510/001 government specification

Shelf Life:

N/a

Unit Of Measure:

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Yes - demil/mli

Fiig:

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